

# **Voltage Regulator** - Low Noise, RF LDO

#### 1 A

### NCP59800

The NCP59800 is a 1 A low-dropout linear regulators (LDOs) offering high power-supply ripple rejection (PSRR) and ultra-low output noise. This LDO uses an advanced BiCMOS process to achieve very good electrical performance. It is an ideal choice for noise sensitive Analog RF Front-Ends used in Telecom Equipment. The NCP59800 is available in the 3 mm x 3 mm DFN8 package.

#### **Features**

- Operating Input Voltage Range: 2.2 V to 6.0 V
- Output Voltage Range: 0.8 V to 5 V (adjustable)
- Quiescent Current typ. 60 μA
- Low Dropout: 200 mV typ. at 1 A,  $V_{OUT} = 2.5 \text{ V}$
- ±2.5% V<sub>OUT</sub> Accuracy across Load/Line/Temperature
- Stable with Small 4.7 μF Ceramic Capacitors
- Very-Low Noise: Typically 15 μV<sub>RMS</sub> from 100 Hz to 100 kHz
- Over-Current and Thermal Shutdown Protection
- Available in 3 x 3 mm DFN8 Package
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

#### **Typical Applications**

- Telecom Infrastructure
- Audio
- High-Speed I/F (PLL/VCO)

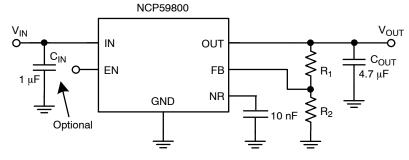


Figure 1. Typical Application Schematics



DFN8 3 x 3 mm CASE 506DB

#### **MARKING DIAGRAM**



= Assembly Location

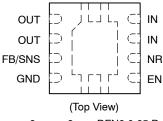
L = Wafer Lot Y = Year

Α

W = Work Week
■ Pb-Free Package

(Note: Microdot may be in either location)

#### **PIN CONNECTIONS**



3 mm x 3 mm DFN8 0.65 P

#### **ORDERING INFORMATION**

See detailed ordering and shipping information on page 9 of this data sheet.

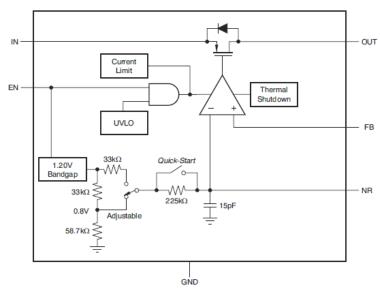


Figure 2. Internal Block Diagram

**Table 1. PIN FUNCTION DESCRIPTION** 

Pin No. DFN8	Pin Name	Description
7,8	IN	Unregulated input supply.
4, EPAD	GND	Ground.
5	EN	Driving the enable pin (EN) high turns on the regulator. Driving this pin low puts the regulator into shutdown mode.
6	NR	Connect an external capacitor between this pin and ground to reduce the output noise to very low levels. The capacitor slows down the $V_{OUT}$ ramp as well (soft–start). Max recommended $C_{NR}$ value is 0.47 $\mu F$
3	FB	This pin is the input to the control loop error amplifier and is used to set the output voltage of the device.
1,2	OUT	Regulator output. A 4.7 μF to 100 μF capacitor is required for stability.

**Table 2. ABSOLUTE MAXIMUM RATINGS** 

Rating	Symbol	Value	Unit
Input Voltage (Note 1)	IN	6.5	V
Output Voltage	OUT	$-0.3$ to $(V_{IN} + 0.3) \le 6.5$	V
Enable Input Voltage	EN	-0.3 to 6.5	V
FB Input Voltage	FB	-0.3 to 3.6	V
Output Current	I <sub>OUT</sub>	Internally Limited	mA
Maximum Junction Temperature	T <sub>J(MAX)</sub>	150	°C
Operating Ambient Temperature Range	T <sub>A</sub>	-40 to +125	°C
Storage Temperature	T <sub>STG</sub>	-55 to 150	°C
ESD Capability, Human Body Model (Note 2)	ESD <sub>HBM</sub>	2000	V
ESD Capability, Machine Model (Note 2)	ESD <sub>MM</sub>	200	V

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- 1. Refer to ELECTRICAL CHARACTERISTICS and APPLICATION INFORMATION for Safe Operating Area.
- 2. This device series incorporates ESD protection and is tested by the following methods:
  - ESD Human Body Model tested per AEC-Q100-002 (EIA/JESD22-A114)
  - ESD Machine Model tested per AEC-Q100-003 (EIA/JESD22-A115)
  - Latchup Current Maximum Rating tested per JEDEC standard: JESD78

#### Table 3. RECOMMENDED OPERATING CONDITIONS

Parameter	Symbol	Min	Max	Unit
Input Voltage	V <sub>IN</sub>	$\left(V_{OUT} + V_{DO}\right) \geq 2.2$	6.0	٧
Junction Temperature	$T_J$	-40	+125	°C

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

#### **Table 4. THERMAL CHARACTERISTICS**

Rating	Symbol	Value	Unit
Thermal Characteristics, DFN8 3 mm x 3 mm Thermal Resistance, Junction-to-Air (Note 3)	$R_{ hetaJA}$	52	°C/W

<sup>3.</sup> The junction-to-ambient thermal resistance under natural convection is obtained in a simulation on a JEDEC-standard, high-K board, as specified in JESD51-7, in an environment described in JESD51-2a.

**Table 5. ELECTRICAL CHARACTERISTICS** Over the operating temperature range of  $T_J = -40^{\circ}\text{C}$  to  $+125^{\circ}\text{C}$ ,  $V_{IN} = (V_{OUT(NOM)} + 0.5 \text{ V})$  or 2.2 V (whichever is greater),  $I_{OUT} = 1$  mA,  $V_{EN} = 2.2$  V,  $C_{OUT} = 4.7$   $\mu\text{F}$ , and  $C_{NR} = 0.01$   $\mu\text{F}$ , unless otherwise noted. NCP59800 Adjustable device is tested at  $V_{OUT} = 0.8$  V and  $V_{OUT} = 5.0$  V. Typical values are at  $T_J = +25^{\circ}\text{C}$ .

Parameter	Test Condition	s	Symbol	Min	Тур	Max	Unit
Input Voltage Range			V <sub>IN</sub>	(V <sub>OUT</sub> +V <sub>DO</sub> ) ≥ 2.2		6.0	V
Internal Reference			$V_{NR}$		0.8		V
Output Voltage	Adjustable		V <sub>OUT</sub>	0.8		5.0	V
Output Voltage Accuracy (Note 4)	$V_{OUT} + 0.5 \text{ V} \le V_{IN} \le 6.0 \text{ V}, V_{IM} \le 100 \text{ V}$	/ <sub>IN</sub> ≥ 2.2 V	V <sub>OUT</sub>	-2.5	±0.3	+2.5	%
Line Regulation	$V_{OUT} + 0.5 \text{ V} \le V_{IN} \le 6.0 \text{ V}, \text{ V}$ $I_{OUT} = 1 \text{ mA}$	/ <sub>IN</sub> ≥ 2.2 V	ΔVουτ/ ΔVιν		150		μV/V
Load Regulation	1 mA ≤ I <sub>OUT</sub> ≤ 1 A		ΔVουτ/ ΔΙουτ		2.0		μV/mA
Dropout Voltage	$V_{OUT} + 0.5 \text{ V} \le V_{IN} \le 6.0 \text{ V}, V_{IN} \ge 2.2 \text{ V}$ $I_{OUT} = 500 \text{ mA}, V_{FB} = \text{GND}$		V <sub>DO</sub>			250	mV
	$V_{OUT} + 0.5 \text{ V} \le V_{IN} \le 6.0 \text{ V}, V_{IN} \ge 2.5 \text{ V}$ $I_{OUT} = 750 \text{ mA}, V_{FB} = \text{GND}$		]			350	mV
	$V_{OUT} + 0.5 \text{ V} \le V_{IN} \le 6.0 \text{ V}, V_{IN} \ge 2.5 \text{ V}$ $I_{OUT} = 1 \text{ A}, V_{FB} = \text{GND}$					500	mV
Output Current Limit	V <sub>OUT</sub> = 0.85 V <sub>OUT(NOM)</sub> , V <sub>IN</sub> ≥ 3.3 V		I <sub>CL</sub>	1.1	1.6	2.5	Α
Ground Pin Current	I <sub>OUT</sub> = 0.1 mA		I <sub>GND</sub>		60	100	μΑ
	I <sub>OUT</sub> = 1 A		1			450	μΑ
Shutdown Current (I <sub>GND</sub> )	$V_{EN} \le 0.4 \text{ V}, V_{IN} \ge 2.2 \text{ V}, R_L = 0^{\circ}\text{C} \le T_J \le 85^{\circ}\text{C}$	= 1 kΩ,	I <sub>SHDN</sub>		0.2	2.0	μА
Feedback Pin Current	V <sub>IN</sub> = 6.0 V, V <sub>FB</sub> = 0.8 V				0.02	1.0	μΑ
Power Supply Rejection Ratio	I <sub>OUT</sub> = 750 mA, V <sub>OUT</sub> = 3.3 V, V <sub>IN</sub> = 4.3 V	f = 100 Hz f = 1 kHz f = 1 MHz	PSRR		77 63 27		dB
Output Noise Voltage	BW = 100 Hz-100 kHz, I <sub>OUT</sub> = 100 mA, C <sub>NR</sub> = 100 nF, V <sub>IN</sub> = 4.3 V, V <sub>OUT</sub> = 3.3 V		V <sub>N</sub>		15 x V <sub>OUT</sub>		μV <sub>RMS</sub>
Enable Input Current	V <sub>IN</sub> = V <sub>EN</sub> = 6.0 V		I <sub>EN</sub>		0.02	1.0	μΑ
Soft-Start Charging Current	V <sub>NR</sub> = 0.5 V		I <sub>SS</sub>		7.2		μΑ
EN Pin Threshold Voltage	EN Input Voltage "H"		V <sub>ENH</sub>	1.2			V
	EN Input Voltage "L"		V <sub>ENL</sub>			0.4	1

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

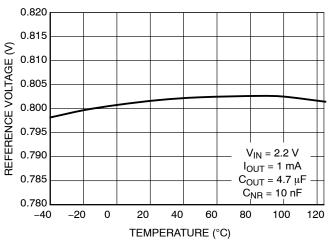
As for NCP59800 (adjustable); it does not include external resistor tolerances and it is not tested at this condition:
 V<sub>OUT</sub> = 0.8 V, 4.5 V ≤ V<sub>IN</sub> ≤ 6.0 V, and 750 mA ≤ I<sub>OUT</sub> ≤ 1 A because of power dissipation higher than maximum rating of the package.

**Table 5. ELECTRICAL CHARACTERISTICS** Over the operating temperature range of  $T_J = -40^{\circ}\text{C}$  to +125°C,  $V_{IN} = (V_{OUT(NOM)} + 0.5 \text{ V})$  or 2.2 V (whichever is greater),  $I_{OUT} = 1$  mA,  $V_{EN} = 2.2$  V,  $C_{OUT} = 4.7 \,\mu\text{F}$ , and  $C_{NR} = 0.01 \,\mu\text{F}$ , unless otherwise noted. NCP59800 Adjustable device is tested at  $V_{OUT} = 0.8$  V and  $V_{OUT} = 5.0$  V. Typical values are at  $T_J = +25^{\circ}\text{C}$ .

Parameter	Test Conditions		Symbol	Min	Тур	Max	Unit
Start-Up Time	V <sub>OUT(NOM)</sub> = 3.3 V V <sub>OUT</sub> = 0% to 90%	C <sub>NR</sub> = 10 nF	t <sub>STR</sub>		1.0		ms
	$V_{OUT(NOM)}$ $R_L = 3.3$ k $\Omega$ , $C_{OUT}$ =4.7 μF	C <sub>NR</sub> = 100 nF			10		ms
Undervoltage Lockout	$V_{IN}$ rising, $R_L = 1 \text{ k}\Omega$		UVLO	1.86	2.0	2.1	V
UVLO Hysteresis	$V_{IN}$ falling, $R_L = 1 \text{ k}\Omega$				75		mV
Thermal Shutdown	Shutdown, temperature increasing		T <sub>SD_TEMP</sub>		160		°C
Thermal Shutdown Recovery	Reset, temperature decreasing		T <sub>SD_HYST</sub>		140		
T <sub>J</sub> Operating Range				-40		+125	°C

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

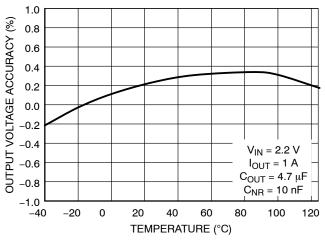
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 V<sub>OUT</sub> = 0.8 V, 4.5 V ≤ V<sub>IN</sub> ≤ 6.0 V, and 750 mA ≤ I<sub>OUT</sub> ≤ 1 A because of power dissipation higher than maximum rating of the package.



1.0 8 0.8 VOLTAGE ACCURACY 0.6 0.4 0.2 0.0 -0.2 -0.4  $V_{IN}$  = 2.2 VOUTPUT  $I_{OUT} = 1 \text{ mA}$ -0.6 C<sub>OUT</sub> = 4.7 μF -0.8 C<sub>NR</sub> = 10 nF -1.0 -40 -20 20 40 60 100 120 TEMPERATURE (°C)

Figure 3. Output Voltage vs. Temperature – V<sub>OUT</sub> = 0.8 V (Adjustable reference)

Figure 4. Output Voltage Accuracy vs. Temperature



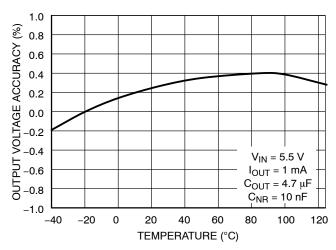
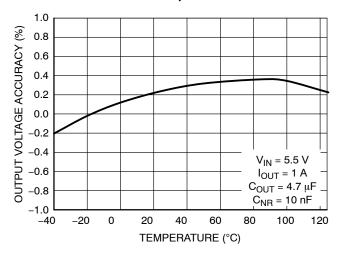


Figure 5. Output Voltage Accuracy vs. Temperature

Figure 6. Output Voltage Accuracy vs.
Temperature



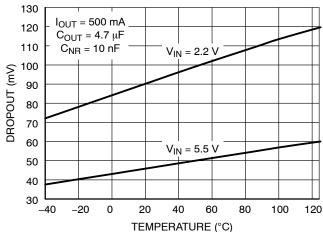
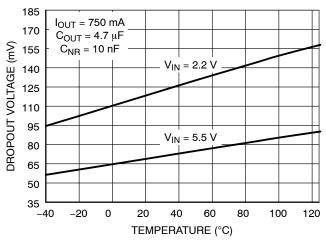


Figure 7. Output Voltage Accuracy vs.
Temperature

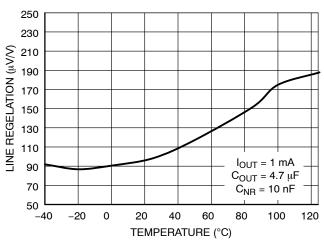
Figure 8. Dropout Voltage vs. Temperature – I<sub>OUT</sub> = 500 mA



250  $I_{OUT} = 1 A$ 230 C<sub>OUT</sub> = 4.7 μF DROPOUT VOLTAGE (mV) 210  $C_{NR} = 10 \text{ nF}$  $V_{1N} = 2.2 \text{ V}$ 190 170 150 130  $V_{IN} = 5.5 \text{ V}$ 110 90 70 50 -40 -20 0 20 40 60 80 100 120 TEMPERATURE (°C)

Figure 9. Dropout Voltage vs. Temperature – I<sub>OUT</sub> = 750 mA

Figure 10. Dropout Voltage vs. Temperature –  $I_{OUT} = 1 A$ 



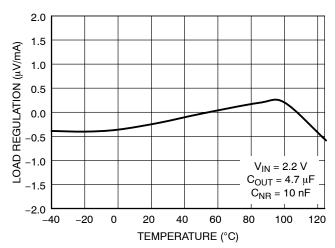
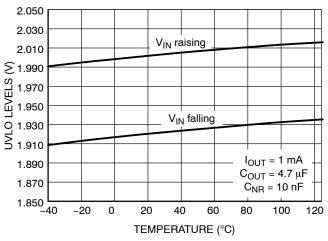


Figure 11. Line Regulation vs. Temperature

Figure 12. Load Regulation vs. Temperature



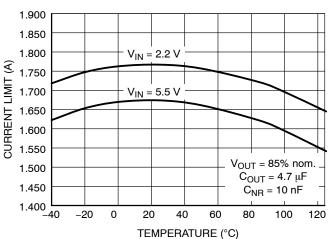
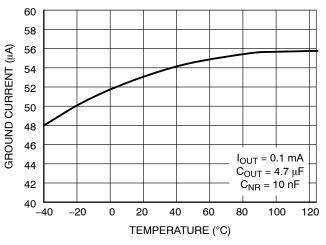


Figure 13. UVLO Thresholds vs. Temperature

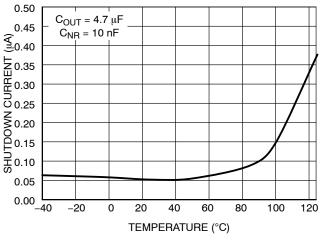
Figure 14. Current Limit vs. Temperature



350 340 GROUND CURRENT (µA) 330 320 310 300 290 280  $I_{OUT} = 1 A$ 270  $C_{OUT}$  = 4.7  $\mu F$ 260  $C_{NR} = 10 \text{ nF}$ 250 <del>-</del>40 -20 0 20 40 60 80 100 120 TEMPERATURE (°C)

Figure 15. Ground Current vs. Temperature

Figure 16. Ground Current vs. Temperature



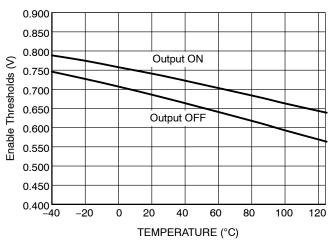
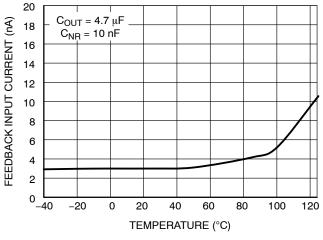


Figure 17. Shutdown Current vs. Temperature

Figure 18. Enable Thresholds vs. Temperature



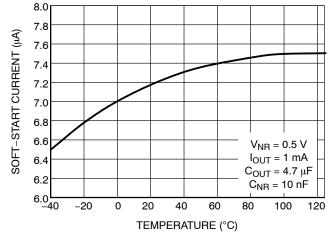


Figure 19. Feedback Input Current vs. Temperature (Adjustable Option)

Figure 20. Soft-Start Current vs. Temperature

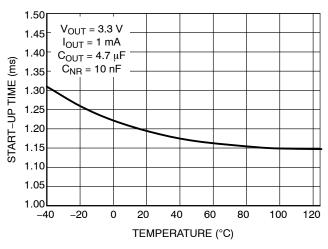


Figure 21. Start-up Time vs. Temperature

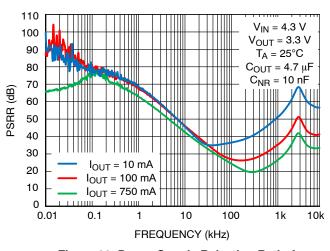


Figure 22. Power Supply Rejection Ratio for  $V_{OUT}$  = 3.3 V,  $C_{OUT}$  = 4.7  $\mu$ F,  $C_{NR}$  = 10 nF

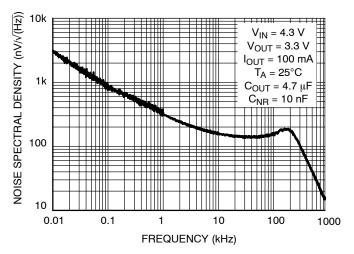


Figure 23. Output Voltage Noise Spectral Density for  $V_{OUT}$  = 3.3 V,  $C_{OUT}$  = 4.7  $\mu F$ ,  $C_{NR}$  = 100 nF

#### **APPLICATIONS INFORMATION**

#### **General Information**

The NCP59800 regulator is equipped with Noise Reduction pin (NR) for noise sensitive applications. A noise reduction capacitor ( $C_{NR}$ ) at the NR pin bypasses noise generated by the bandgap reference. This family of regulators offers sub-bandgap output voltages, current limit, and thermal protection, and is fully specified from  $-40^{\circ}\text{C}$  to  $+125^{\circ}\text{C}$ , assuming resistors with zero error. For the actual design, pay attention to any resistor error factors. Figure 24 gives the Typical Application Schematics.

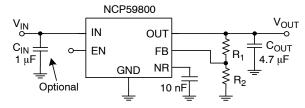


Figure 24. Typical Application Schematics

#### **Output Voltage Setting**

The output voltage can be adjusted from 0.8 V to 5.0 V using resistors divider between the output and the FB input. The values of R1 and R2 can be calculated for any voltage using the following formula:

$$V_{OUT} = 0.8 V \left( 1 + \frac{R_1}{R_2} \right)$$

Recommended resistor values for frequently used voltages can be found in the Table 6.

#### **Capacitors Selection**

Although an input capacitor is not required for stability, it is good analog design practice to connect a 0.1  $\mu F$  to 1.0  $\mu F$  low equivalent series resistance (ESR) capacitor across the input supply near the regulator. The NCP59800 is designed to be stable with standard ceramic output capacitors of

capacitance values 4.7  $\mu F$  up to 100  $\mu F$ . This device is evaluated using a 4.7  $\mu F/10$  V, 10% tolerance, X5R type Ceramic Capacitors of 0805 size.

X5R- and X7R-type capacitors are highly recommended because they have minimal variation in value and ESR over temperature.

#### **Startup Response**

The  $C_{NR}$  serves not only for noise reduction. During Start-Up the  $C_{NR}$  capacitor works like the Soft Start timing capacitor. The controlled monotonic ramping of Voltage Reference (adjustable Soft-Start) is limiting the Inrush Current.

Table 6. RECOMMENDED 1% FEEDBACK RESISTOR Values for Frequently Used Nominal Output Voltages

Vouт	R <sub>1</sub>	R <sub>2</sub>
0.8 V	0 Ω (Short)	10.0 kΩ
1.0 V	2.49 kΩ	10.0 kΩ
1.2 V	4.99 kΩ	10.0 kΩ
1.5 V	8.87 kΩ	10.0 kΩ
1.8 V	12.5 kΩ	10.0 kΩ
2.5 V	21.0 kΩ	10.0 kΩ
3.3 V	30.9 kΩ	10.0 kΩ
5.0 V	52.3 kΩ	10.0 kΩ

#### **Power Dissipation**

The maximum power dissipation supported by the device is dependent upon board design and layout. Mounting pad configuration on the PCB, the board material, and the ambient temperature affect the rate of junction temperature rise for the part. For reliable operation junction temperature should be limited to +125°C.

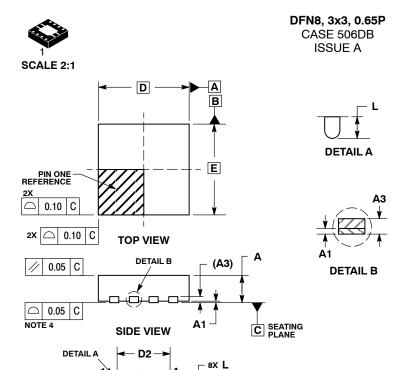
**Table 7. ORDERING INFORMATION** 

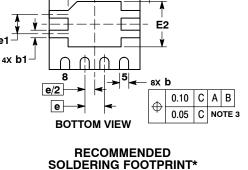
Device	Output Voltage	Marking	Package	Shipping <sup>†</sup>
NCP59800BMNADJTAG	ADJ	59800 ADJB	DFN8 3x3	2000/Tong 9 Dog
NCP59800BMNADJTBG	ADJ	59800 ADJB	(Pb-Free)	3000/Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

NOTE: The A or B letter in the device suffix represents part orientation in the tape.

<sup>\*</sup>To order other package and voltage variants, please contact your ON sales representative.





#### 3 30 2.05 0.63 PACKAGE OUTLINE 3.30 1 64 0.65

0.65 **PITCH** DIMENSIONS: MILLIMETERS \*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and

Mounting Techniques Reference Manual, SOLDERRM/D.

12X 0.40

**DATE 12 OCT 2016** 

#### NOTES:

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
  CONTROLLING DIMENSION: MILLIMETERS.
- DIMENSION & APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND
- 0.30mm FROM THE TERMINAL TIP.
  COPLANARITY APPLIES TO THE EXPOSED
  PAD AS WELL AS THE TERMINALS.

		MILLIMETERS			
	DIM	MIN	MAX		
	Α	0.80	1.00		
	A1	0.00	0.05		
	АЗ	0.20	REF		
	b	0.25	0.35		
	b1	0.20	0.30		
	D	3.00	BSC		
	D2	1.65	1.85		
L	Е	3.00	BSC		
	E2	1.40	1.60		
	е	0.65	BSC		
	e1	0.65 REF			
	L	0.30	0.50		
	L1	0.00	0.15		

#### **GENERIC MARKING DIAGRAM\***



XXXXX = Specific Device Code

= Assembly Location Α

= Wafer Lot L Υ = Year W = Work Week = Pb-Free Package

(Note: Microdot may be in either location)

\*This information is generic. Please refer to device data sheet for actual part marking.

Pb-Free indicator, "G" or microdot " ■", may or may not be present.

DOCUMENT NUMBER:	98AON92252F	Electronic versions are uncontrolled except when accessed directly from the Document Reposit Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.			
DESCRIPTION:	DFN8, 3X3, 0.65P		PAGE 1 OF 1		

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